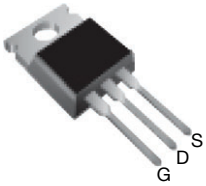
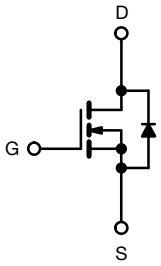
Power MOSFET

TO-220AB





N-Channel MOSFET

FEATURES

- Dynamic dV/dt rating
- Repetitive avalanche rated
- Logic-level gate drive
- $R_{DS(on)}$ specified at V_{GS} = 4 V and 5 V
- Fast switching
- Ease of paralleling
- Simple drive requirements
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

Available

RoHS* Available

Note

* This datasheet provides information about parts that are RoHS-compliant and / or parts that are non RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information / tables in this datasheet for details

DESCRIPTION

Third generation power MOSFETs from Vishay provides the designer with the best combination of fast switching, ruggedized device design, low on-resistance and cost effectiveness.

The TO-220AB package is universally preferred for all commercial-industrial applications at power dissipation levels to approximately 50 W. The low thermal resistance and low package cost of the TO-220AB contribute to its wide acceptance throughout the industry.

PRODUCT SUMMARY		
V_{DS} (V)	200	
$R_{DS(on)}$ (Ω)	V_{GS} = 5.0 V	0.18
Q_g max. (nC)	66	
Q_{gs} (nC)	9.0	
Q_{gd} (nC)	38	
Configuration	Single	

ORDERING INFORMATION	
Package	TO-220AB
Lead (Pb)-free	IRL640PbF
Lead (Pb)-free and halogen-free	IRL640PbF-BE3

ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted)

PARAMETER			SYMBOL	LIMIT	UNIT
Drain-source voltage			V_{DS}	200	V
Gate-source voltage			V_{GS}	± 10	
Continuous drain current	V_{GS} at 5 V	T_C = 25 °C	I_D	17	A
		T_C = 100 °C		11	
Pulsed drain current [a]			I_{DM}	68	
Linear derating factor				1.0	W/°C
Single pulse avalanche energy [b]			E_{AS}	580	mJ
Repetitive avalanche current [a]			I_{AR}	10	A
Repetitive avalanche energy [a]			E_{AR}	13	mJ
Maximum power dissipation	T_C = 25 °C		P_D	125	W
Peak diode recovery dV/dt [c]			dV/dt	5.0	V/ns
Operating junction and storage temperature range			T_J, T_{stg}	-55 to +150	°C
Soldering recommendations (peak temperature) [d]	For 10 s			300	
Mounting torque	6-32 or M3 screw			10	lbf · in
				1.1	N · m

Notes

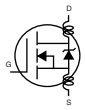
a. Repetitive rating; pulse width limited by maximum junction temperature (see fig. 11)
b. V_{DD} = 50 V, starting T_J = 25 °C, L = 3.0 mH, R_g = 25 Ω I_{AS} = 17 A (see fig. 12)
c. I_{SD} ≤ 17 A, dI/dt ≤ 150 A/ms, V_{DD} ≤ V_{DS}, T_J ≤ 150 °C

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d. 1.6 mm from case

THERMAL RESISTANCE RATINGS				
PARAMETER	**SYMBOL**	**TYP.**	**MAX.**	**UNIT**
Maximum junction-to-ambient	R_{thJA}	-	62	°C/W
Case-to-sink, flat, greased surface	R_{thCS}	0.50	-	
Maximum junction-to-case (drain)	R_{thJC}	-	1.0	

SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)						
PARAMETER	**SYMBOL**	**TEST CONDITIONS**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static						
Drain-source breakdown voltage	V_{DS}	V_{GS} = 0 V, I_D = 250 µA	200	-	-	V
V_{DS} temperature coefficient	$\Delta V_{DS}/T_J$	Reference to 25 °C, I_D = 1 mA	-	0.27	-	V/°C
Gate-source threshold voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 µA	1.0	-	2.0	V
Gate-source leakage	I_{GSS}	V_{GS} = ± 10	-	-	± 100	nA
Zero gate voltage drain current	I_{DSS}	V_{DS} = 200 V, V_{GS} = 0 V	-	-	25	µA
		V_{DS} = 160 V, V_{GS} = 0 V, T_J = 125 °C	-	-	250	
Drain-source on-state resistance	$R_{DS(on)}$	V_{GS} = 5.0 V, I_D = 10 A [b]	-	-	0.18	Ω
		V_{GS} = 4.0 V, I_D = 8.5 A [b]	-	-	0.27	
Forward transconductance	g_{fs}	V_{DS} = 50 V, I_D = 10 A [b]	16	-	-	S
Dynamic						
Input capacitance	C_{iss}	V_{GS} = 0 V, V_{DS} = 25 V, f = 1.0 MHz, see fig. 5	-	1800	-	pF
Output capacitance	C_{oss}		-	400	-	
Reverse transfer capacitance	C_{rss}		-	120	-	
Total gate charge	Q_g	V_{GS} = 5.0 V, I_D = 17 A, V_{DS} = 160 V, see fig. 6 and 13 [b]	-	-	66	nC
Gate-source charge	Q_{gs}		-	-	9.0	
Gate-drain charge	Q_{gd}		-	-	38	
Turn-on delay time	$t_{d(on)}$	V_{DD} = 100 V, I_D = 17 A, R_g = 4.6 Ω, R_D = 5.7 Ω, see fig. 10 [b]	-	8.0	-	ns
Rise time	t_r		-	83	-	
Turn-off delay time	$t_{d(off)}$		-	44	-	
Fall time	t_f		-	52	-	
Internal drain inductance	L_D	Between lead, 6 mm (0.25") from package and center of die contact 	-	4.5	-	nH
Internal source inductance	L_S		-	7.5	-	
Gate input resistance	R_g	f = 1 MHz, open drain	0.3	-	1.2	Ω
Drain-Source Body Diode Characteristics						
Continuous source-drain diode current	I_S	MOSFET symbol showing the integral reverse p - n junction diode 	-	-	17	A
Pulsed diode forward current [a]	I_{SM}		-	-	68	
Body diode voltage	V_{SD}	T_J = 25 °C, I_S = 17 A, V_{GS} = 0 V [b]	-	-	2.0	V
Body diode reverse recovery time	t_{rr}	T_J = 25 °C, I_F = 17 A, dI/dt = 100 A/µs [b]	-	310	470	ns
Body diode reverse recovery charge	Q_{rr}		-	3.2	4.8	µC
Forward turn-on time	t_{on}	Intrinsic turn-on time is negligible (turn-on is dominated by L_S and L_D)				

Notes

a. Repetitive rating; pulse width limited by maximum junction temperature (see fig. 11)

b. Pulse width ≤ 300 µs; duty cycle ≤ 2 %

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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

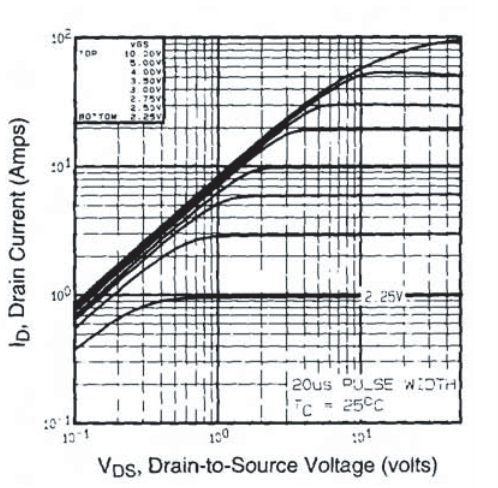


Fig. 1 - Typical Output Characteristics, T_C = 25 °C

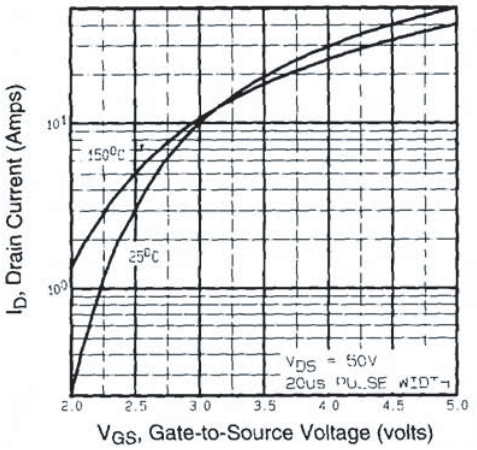


Fig. 3 - Typical Transfer Characteristics

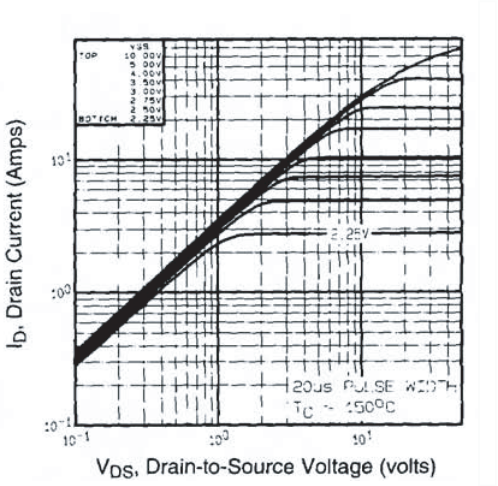


Fig. 2 - Typical Output Characteristics, T_C = 150 °C

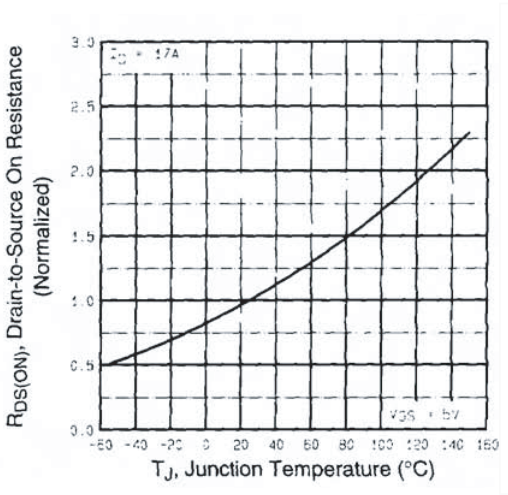


Fig. 4 - Normalized On-Resistance vs. Temperature

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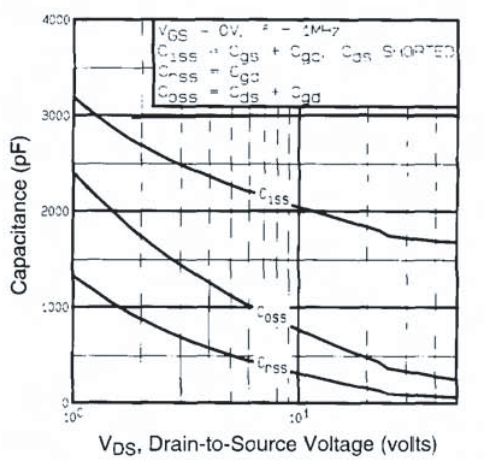


Fig. 5 - Typical Capacitance vs. Drain-to-Source Voltage

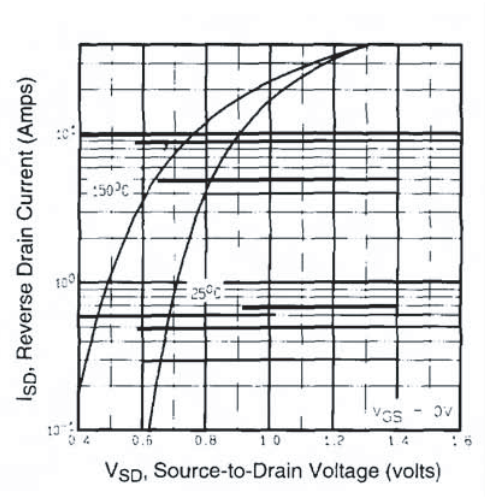


Fig. 7 - Typical Source-Drain Diode Forward Voltage

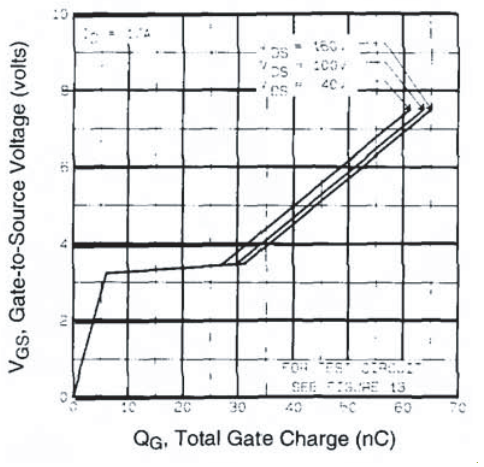


Fig. 6 - Typical Gate Charge vs. Gate-to-Source Voltage

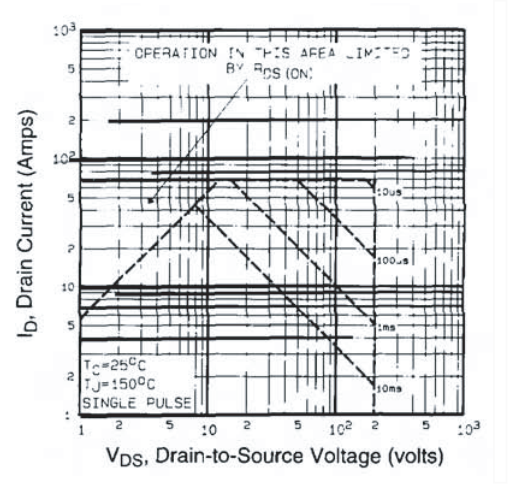


Fig. 8 - Maximum Safe Operating Area

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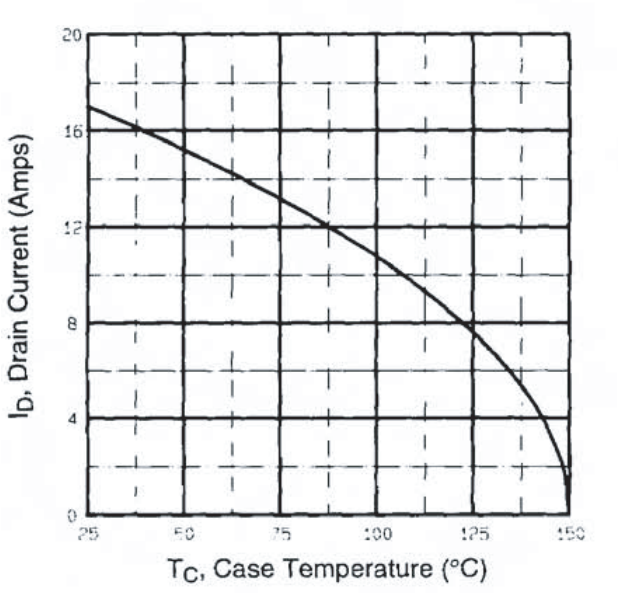


Fig. 9 - Maximum Drain Current vs. Case Temperature

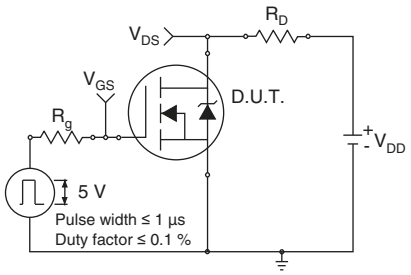


Fig. 10a - Switching Time Test Circuit

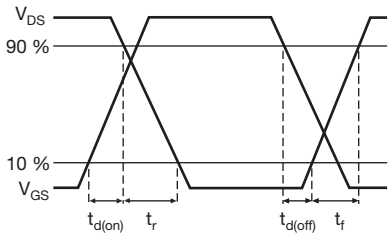


Fig. 10b - Switching Time Waveforms

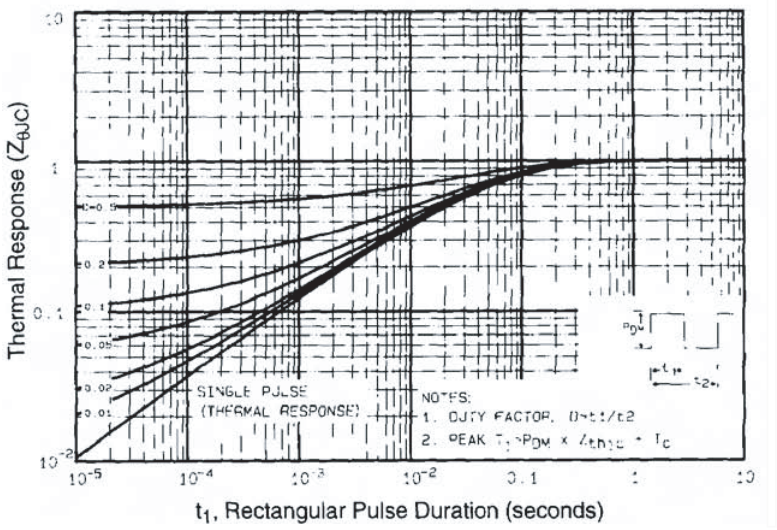


Fig. 11 - Maximum Effective Transient Thermal Impedance, Junction-to-Case

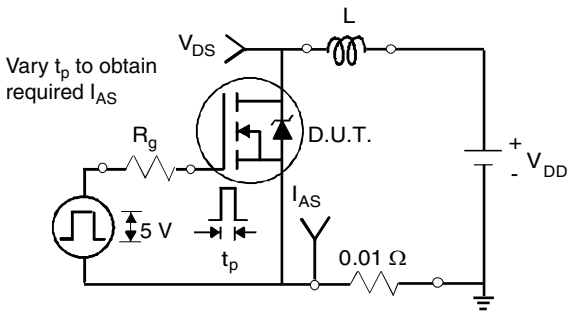


Fig. 12a - Unclamped Inductive Test Circuit

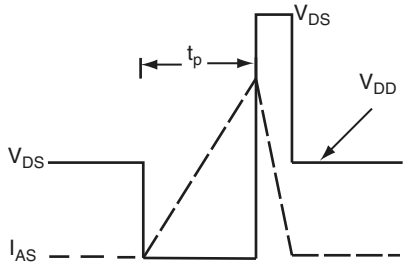


Fig. 12b - Unclamped Inductive Waveforms

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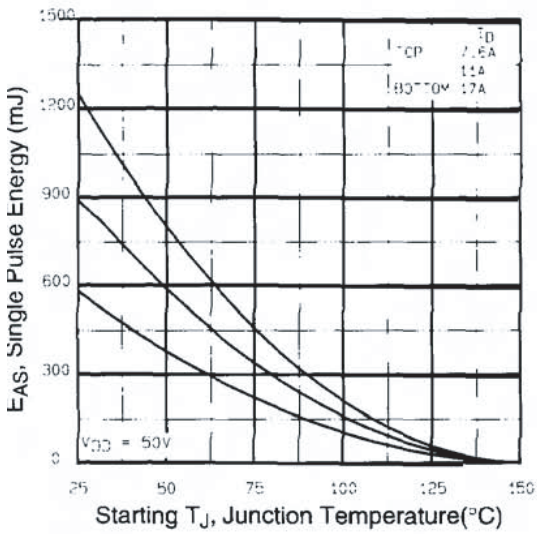


Fig. 12c - Maximum Avalanche Energy vs. Drain Current

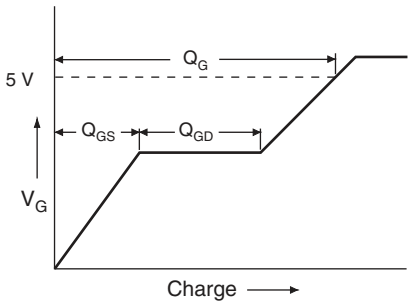


Fig. 13a - Basic Gate Charge Waveform

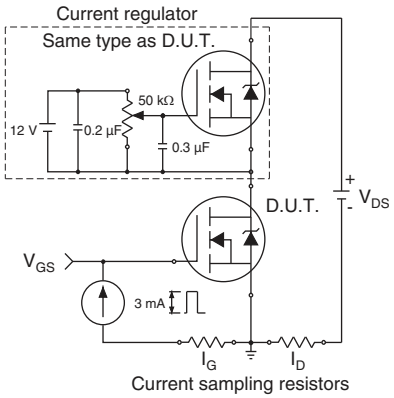


Fig. 13b - Gate Charge Test Circuit

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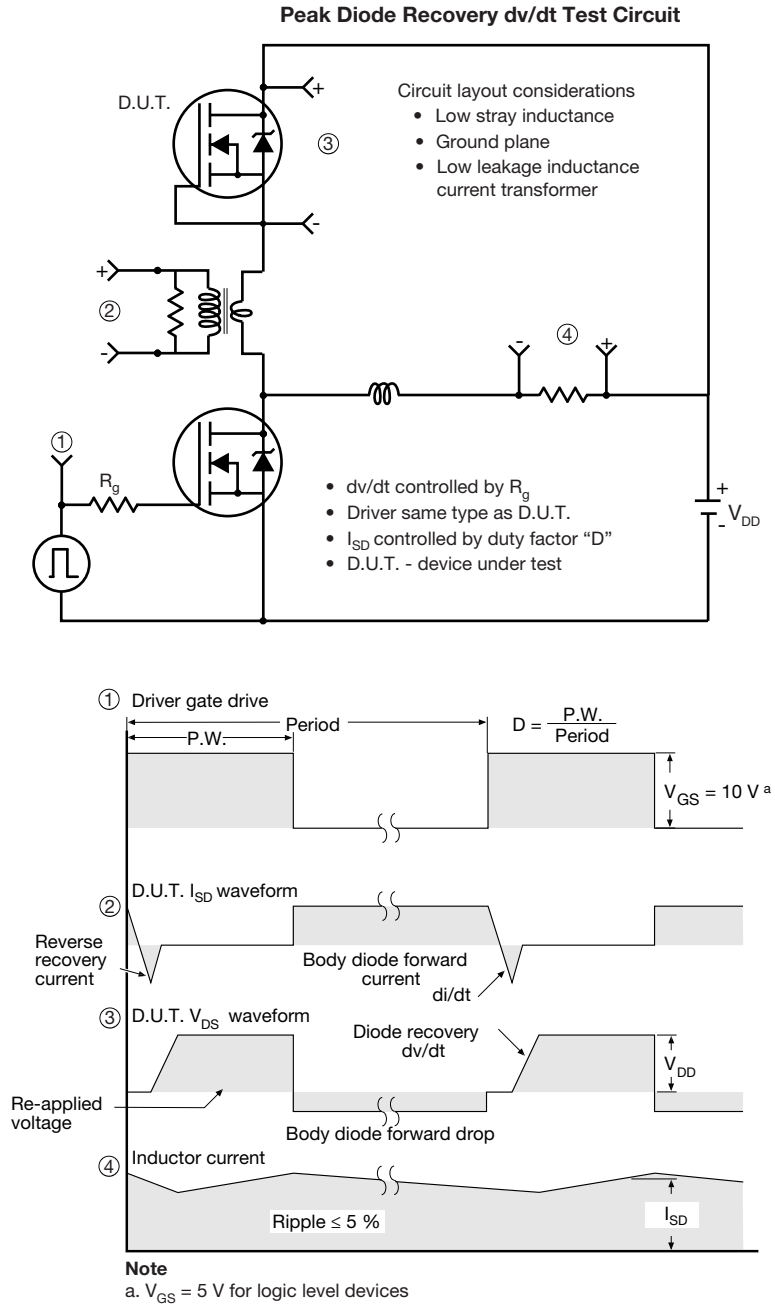


Fig. 14 - For N-Channel

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